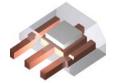


Features and Benefits

- Low-noise output
- Fast power-on time
- Ratiometric rail-to-rail output
- 4.5 to 6.0 V operation
- Solid-state reliability
- Factory-programmed at end-of-line for optimum performance
- Robust ESD performance

Packages: 3 pin SOT23W (suffix LH), and 3 pin SIP (suffix UA)





Not to scale

Description

The A1301 and A1302 are continuous-time, ratiometric, linear Hall-effect sensors. They are optimized to accurately provide a voltage output that is proportional to an applied magnetic field. These devices have a quiescent output voltage that is 50% of the supply voltage. Two output sensitivity options are provided: 2.5 mV/G typical for the A1301, and 1.3 mV/G typical for the A1302.

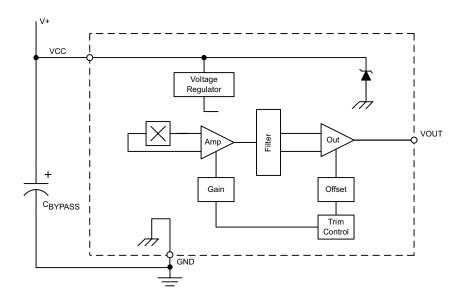
The Hall-effect integrated circuit included in each device includes a Hall sensing element, a linear amplifier, and a CMOS Class A output structure. Integrating the Hall sensing element and the amplifier on a single chip minimizes many of the problems normally associated with low voltage level analog signals.

High precision in output levels is obtained by internal gain and offset trim adjustments made at end-of-line during the manufacturing process.

These features make the A1301 and A1302 ideal for use in position sensing systems, for both linear target motion and rotational target motion. They are well-suited for industrial applications over extended temperature ranges, from -40°C to 125°C.

Two device package types are available: LH, a 3-pin SOT23W type for surface mount, and UA, a 3-pin ultramini SIP for through-hole mount. They are lead (Pb) free (suffix, -T) with 100% matte tin plated leadframes.

Functional Block Diagram



Selection Guide	!					
Part Number	Pb-free ¹	Packing ²	Package	Ambient, T _A	Sensitivity (Typical)	
A1301ELHLT-T	Yes	7-in. tape and reel, 3000 pieces/reel	Surface Mount	-40°C to 85°C		
A1301EUA-T	Yes	Bulk, 500 pieces/bag	SIP	-40°C 10 65°C	2.5 mV/G	
A1301KLHLT-T	Yes	7-in. tape and reel, 3000 pieces/reel	Surface Mount	-40°C to 125°C	2.5 IIIV/G	
A1301KUA-T	Yes	Bulk, 500 pieces/bag	SIP	-40°C to 125°C		
A1302ELHLT-T	Yes	7-in. tape and reel, 3000 pieces/reel	Surface Mount	-40°C to 85°C		
A1302EUA-T	Yes	Bulk, 500 pieces/bag	SIP	-40°C 10 65°C	1.3 mV/G	
A1302KLHLT-T	Yes	7-in. tape and reel, 3000 pieces/reel	Surface Mount	-40°C to 125°C		
A1302KUA-T	Yes	Bulk, 500 pieces/bag	SIP	-40 C (0 125 C		

¹Pb-based variants are being phased out of the product line. Certain variants cited in this footnote are no longer in production. The variants should not be purchased for new design applications. Samples are no longer available. Status change: May 1, 2006. These variants include: A1301ELHLT, A1301EUA, A1301KLHLT, A1301KUA, A1302EUA, A1302KLHLT, and A1302KUA.



Absolute Maximum Ratings

, to o i a to maximum i tamingo					
Characteristic	Symbol	Notes	Rating	Units	
Supply Voltage	V _{cc}		8	V	
Output Voltage	V _{OUT}		8	V	
Reverse Supply Voltage	V _{RCC}		-0.1	V	
Reverse Supply Voltage	V _{RCC}		-0.1	V	
Output Sink Current	I _{OUT}		10	mA	
On a realize of A realize of Tarana a realize		Range E	-40 to 85	°C	
Operating Ambient Temperature	T _A	Range K	-40 to 125	°C	
Maximum Junction Temperature	T _J (max)		165	°C	
Storage Temperature	T _{stg}		-65 to 170	°C	

²Contact Allegro for additional packing options.

A1301 and A1302

Continuous-Time Ratiometric Linear Hall Effect Sensors

DEVICE CHARACTERISTICS over operating temperature range, T_A , and V_{CC} = 5 V, unless otherwise noted

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Electrical Characteristics	•					
Supply Voltage	V _{CC}	Running, T _J < 165°C	4.5	_	6	V
Supply Current	I _{CC}	Output open	—	_	11	mA
0.10.17/11/20	V _{OUT(High)}	I _{SOURCE} = -1 mA, Sens = nominal	4.65	4.7	_	V
Output Voltage	V _{OUT(Low)}	I _{SINK} = 1 mA, Sens = nominal	_	0.2	0.25	V
Output Bandwidth	BW		T -	20	_	kHz
Power-On Time	t _{PO}	V _{CC(min)} to 0.95 V _{OUT;} B = ±1400 G; Slew rate = 4.5 V/µs to 4.5 V/100 ns	_	3	5	μs
Output Resistance	R _{OUT}	I _{SINK} ≤ 1 mA, I _{SOURCE} ≥ −1 mA	_	2	5	Ω
Wide Band Output Noise, rms	V _{OUTN}	External output low pass filter ≤ 10 kHz; Sens = nominal	_	150	_	μV
Ratiometry	•				1	l
Quiescent Output Voltage Error with respect to ΔV_{CC}^1	$\Delta V_{OUTQ(V)}$	T _A = 25°C	_	_	±3.0	%
Magnetic Sensitivity Error with respect to ΔV_{CC}^2	ΔSens _(V)	T _A = 25°C	_	_	±3.0	%
Output	•					
Linearity	Lin	$T_A = 25^{\circ}C$	_	_	±2.5	%
Symmetry	Sym	T _A = 25°C	T -	_	±3.0	%
Magnetic Characteristics	•	•	'		'	
Quiescent Output Voltage	V _{OUTQ}	B = 0 G; T _A = 25°C	2.4	2.5	2.6	V
Quiescent Output Voltage over Operating Temperature Range	$V_{OUTQ(\Delta T_A)}$	B = 0 G	2.2	_	2.8	٧
	Sens	A1301; T _A = 25°C	2.0	2.5	3.0	mV/G
Magnetic Sensitivity		A1302; T _A = 25°C	1.0	1.3	1.6	mV/G
Magnetic Sensitivity over	Sens _(∆T_A)	A1301	1.8	_	3.2	mV/G
Operating Temperature Range		A1302	0.85	_	1.75	mV/G

¹Refer to equation (4) in Ratiometric section on page 4.



²Refer to equation (5) in Ratiometric section on page 4.

Characteristic Definitions

Quiescent Output Voltage. In the quiescent state (no significant magnetic field: B=0), the output, V_{OUTQ} , equals one half of the supply voltage, V_{CC} , throughout the entire operating ranges of V_{CC} and ambient temperature, T_A . Due to internal component tolerances and thermal considerations, there is a tolerance on the quiescent output voltage, ΔV_{OUTQ} , which is a function of both ΔV_{CC} and ΔT_A . For purposes of specification, the quiescent output voltage as a function of temperature, $\Delta V_{OUTQ(\Delta T_A)}$, is defined as:

$$\Delta V_{\text{OUTQ}(\Delta T_{\text{A}})} = \frac{V_{\text{OUTQ}(T_{\text{A}})} - V_{\text{OUTQ}(25^{\circ}\text{C})}}{Sens_{(25^{\circ}\text{C})}}$$
(1)

where Sens is in mV/G, and the result is the device equivalent accuracy, in gauss (G), applicable over the entire operating temperature range.

Sensitivity. The presence of a south-polarity (+B) magnetic field, perpendicular to the branded face of the device package, increases the output voltage, V_{OUT} , in proportion to the magnetic field applied, from V_{OUTQ} toward the V_{CC} rail. Conversely, the application of a north polarity (-B) magnetic field, in the same orientation, proportionally decreases the output voltage from its quiescent value. This proportionality is specified as the magnetic sensitivity of the device and is defined as:

$$Sens = \frac{V_{\text{OUT}(-B)} - V_{\text{OUT}(+B)}}{2B}$$
 (2)

The stability of the device magnetic sensitivity as a function of ambient temperature, $\Delta Sens_{(\Delta T_{\Delta})}$ (%) is defined as:

$$\Delta Sens_{(\Delta T_A)} = \frac{Sens_{(T_A)} - Sens_{(25^{\circ}C)}}{Sens_{(25^{\circ}C)}} \times 100\%$$
 (3)

Ratiometric. The A1301 and A1302 feature a ratiometric output. This means that the quiescent voltage output, V_{OUTQ} , and the magnetic sensitivity, Sens, are proportional to the supply voltage, V_{CC} .

The ratiometric change (%) in the quiescent voltage output is defined as:

$$\Delta V_{\rm OUTQ(\Delta V)} = \frac{V_{\rm OUTQ(V_{CC})} / V_{\rm OUTQ(5V)}}{V_{\rm CC} / 5 \text{ V}} \times 100\%$$
 (4)

and the ratiometric change (%) in sensitivity is defined as:

$$\Delta Sens_{(\Delta V)} = \frac{Sens_{(VCC)} / Sens_{(5V)}}{V_{CC} / 5 V} \times 100\%$$
 (5)

Linearity and Symmetry. The on-chip output stage is designed to provide linear output at a supply voltage of 5 V. Although the application of very high magnetic fields does not damage these devices, it does force their output into a nonlinear region. Linearity in percent is measured and defined as:

$$Lin+ = \frac{V_{\text{OUT(+B)}} - V_{\text{OUTQ}}}{2(V_{\text{OUT(+B/2)}} - V_{\text{VOUTQ}})} \times 100\%$$
 (6)

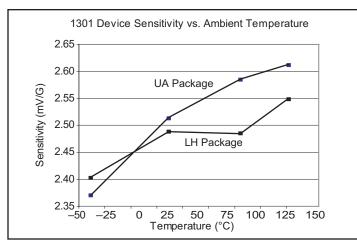
$$Lin- = \frac{V_{\text{OUT(-B)}} - V_{\text{OUTQ}}}{2(V_{\text{OUT(-B'/2)}} - V_{\text{OUTQ}})} \times 100\%$$
 (7)

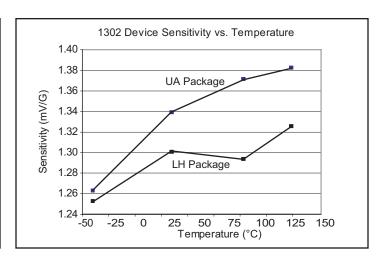
and output symmetry as:

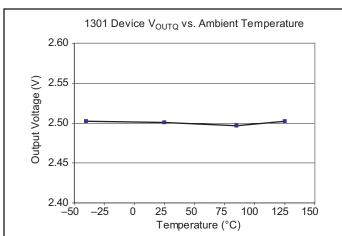
$$Sym = \frac{V_{\text{OUT}(+B)} - V_{\text{OUTQ}}}{V_{\text{OUTO}} - V_{\text{OUT}(-B)}} \times 100\%$$
 (8)

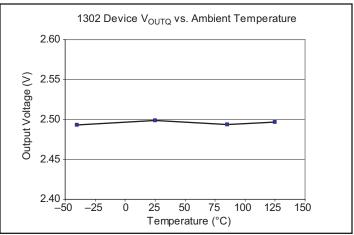


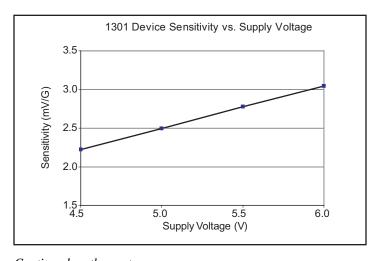
Typical Characteristics (30 pieces, 3 fabrication lots)

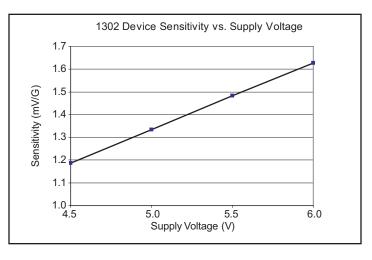








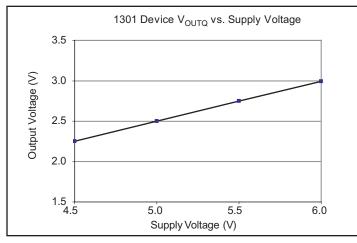


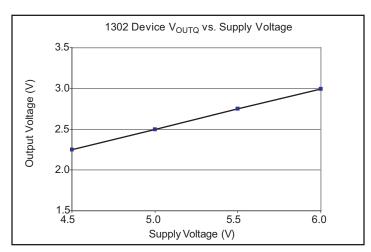


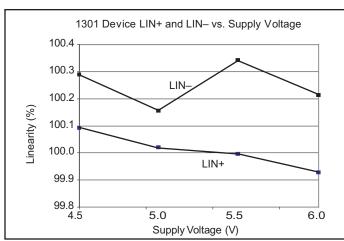
Continued on the next page...

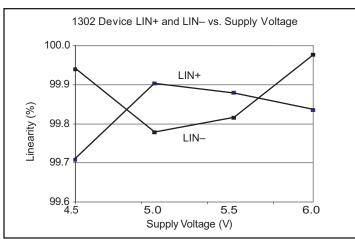


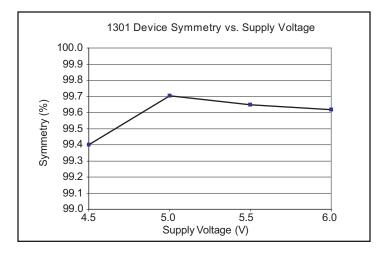
Typical Characteristics, continued (30 pieces, 3 fabrication lots)

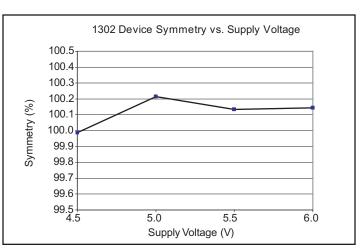




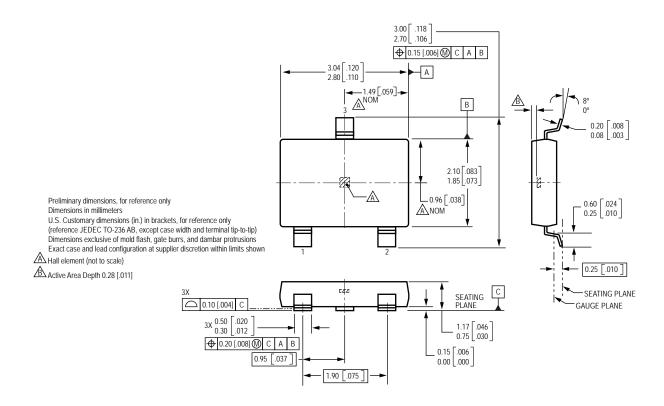




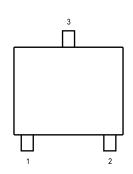




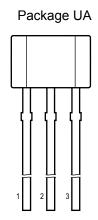
Package LH, 3-Pin; (SOT-23W)



Pin-out Drawings



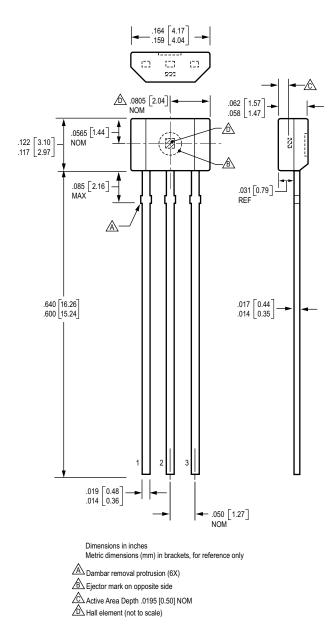
Package LH



Terminal List

Cumbal	Nun	nber	Description	
Symbol	Package LH	Package UA	Description	
VCC	1	1	Connects power supply to chip	
VOUT	2	3	Output from circuit	
GND	3	2	Ground	

Package UA, 3-Pin SIP



The products described herein are manufactured under one or more of the following U.S. patents: 5,045,920; 5,264,783; 5,442,283; 5,389,889; 5,581,179; 5,517,112; 5,619,137; 5,621,319; 5,650,719; 5,686,894; 5,694,038; 5,729,130; 5,917,320; and other patents pending.

Allegro MicroSystems, Inc. reserves the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Before placing an order, the user is cautioned to verify that the information being relied upon is current.

Allegro products are not authorized for use as critical components in life-support devices or systems without express written approval. The information included herein is believed to be accurate and reliable. However, Allegro MicroSystems, Inc. assumes no responsibility for its use; nor for any infringement of patents or other rights of third parties which may result from its use. Copyright © 2005, 2006 Allegro MicroSystems, Inc.

